## 74LVT16373A

### 3.3 V 16-bit transparent D-type latch; 3-state

Rev. 3 — 1 October 2018

Product data sheet

### 1. General description

The 74LVT16373A is a high-performance BiCMOS product designed for  $V_{CC}$  operation at 3.3 V.

This device is a 16-bit transparent D-type latch with non-inverting 3-state bus compatible outputs. The device can be used as two 8-bit latches or one 16-bit latch. When latch enable (LE) input is HIGH, the Q outputs follow the data (D) inputs. When latch enable is taken LOW, the Q outputs are latched at the levels of the D inputs one setup time prior to the HIGH-to-LOW transition.

#### 2. Features and benefits

- 16-bit transparent latch
- 3-state buffers
- Output capability: +64 mA/–32 mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5 V supply
- · Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power-up reset
- Power-up 3-state
- · No bus current loading when output is tied to 5 V bus
- Latch-up protection:
  - JESD78B Class II exceeds 500 mA
- ESD protection:
  - HBM: JESD22-A114F exceeds 2000 V
  - MM: JESD22-A115-A exceeds 200 V

### 3. Ordering information

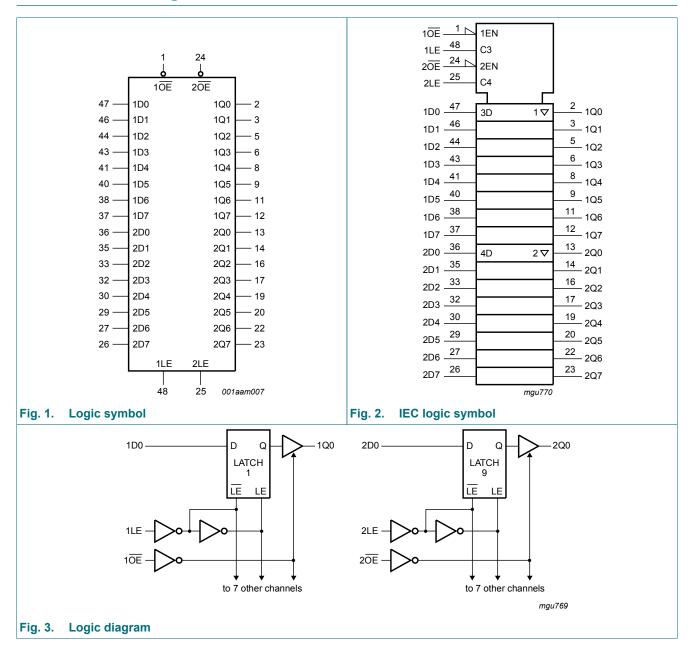
**Table 1. Ordering information** 

Type number	Package	Package									
	Temperature range	Name	Description	Version							
74LVT16373ADL	-40 °C to +85 °C	SSOP48	plastic shrink small outline package; 48 leads; body width 7.5 mm	SOT370-1							
74LVT16373ADGG	-40 °C to +85 °C	TSSOP48	plastic thin shrink small outline package; 48 leads; body width 6.1 mm	SOT362-1							



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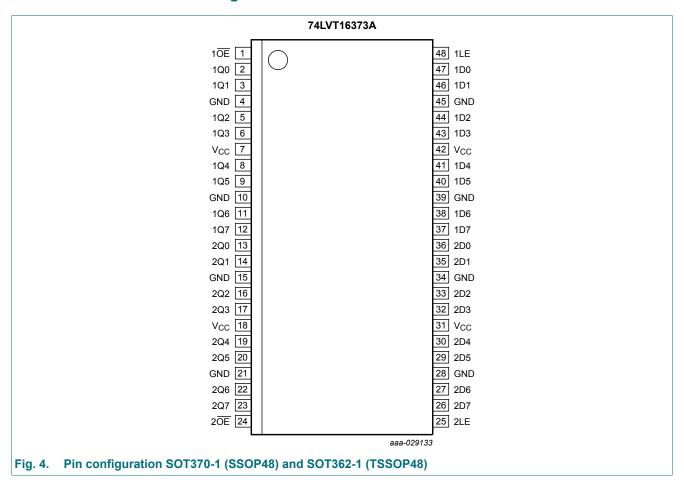
### 4. Functional diagram



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### 5. Pinning information

### 5.1. Pinning



### 5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
1D0, 1D1, 1D2, 1D3, 1D4, 1D5, 1D6, 1D7	47, 46, 44, 43, 41, 40, 38, 37	data inputs
2D0, 2D1, 2D2, 2D3, 2D4, 2D5, 2D6, 2D7	36, 35, 33, 32, 30, 29, 27, 26	data inputs
1Q0, 1Q1, 1Q2, 1Q3, 1Q4, 1Q5, 1Q6, 1Q7	2, 3, 5, 6, 8, 9, 11, 12	data outputs
2Q0, 2Q1, 2Q2, 2Q3, 2Q4, 2Q5, 2Q6, 2Q7	13, 14, 16, 17, 19, 20, 22, 23	data outputs
10E, 20E	1, 24	output enable inputs (active LOW)
1LE, 2LE	48, 25	Latch Enable inputs (active HIGH)
GND	4, 10, 15, 21, 28, 34, 39, 45	ground (0 V)
V <sub>CC</sub>	7, 18, 31, 42	supply voltage

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### 6. Functional description

#### Table 3. Function table [1]

Operating mode	Inputs			Internal	Outputs
	nOE	nLE	nDn	latches	nQn
enable and read register (transparent mode)	L	Н	L	L	L
	L	Н	Н	Н	Н
latch and read register	L	<b>↓</b>	I	L	L
	L	<b>\</b>	h	Н	Н
Hold	L	L	Х	NC	NC
Latch register and disable outputs	Н	L	Х	NC	Z
	Н	Н	nDn	nDn	Z

[1] H = HIGH voltage level;

L = LOW voltage level;

↓ = HIGH-to-LOW LE transition;

h = HIGH voltage level one set-up time prior to the HIGH-to-LOW LE transition;

I = LOW voltage level one set-up time prior to the HIGH-to-LOW LE transition;

X = don't care;

NC = No change;

Z = high-impedance OFF-state.

### 7. Limiting values

### **Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
VI	input voltage	[1]	-0.5	+7.0	V
Vo	output voltage	output in OFF-state or HIGH-state [1]	-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-50	-	mA
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V	-50	-	mA
Io	output current	output in LOW-state	-	128	mA
		output in HIGH-state	-64	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature	[2]	-	+150	°C

<sup>[1]</sup> The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

<sup>[2]</sup> The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.

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### 8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CC</sub>	supply voltage		2.7	-	3.6	V
VI	input voltage		0	-	5.5	V
Δt/ΔV	input transition rise and fall rate	outputs enabled	-	-	10	ns/V
T <sub>amb</sub>	ambient temperature	in free-air	-40	+25	+85	°C

### 9. Static characteristics

### **Table 6. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
V <sub>IK</sub>	input clamping voltage	$V_{CC} = 2.7 \text{ V; } I_{IK} = -18 \text{ mA}$	-	-0.85	-1.2	V
V <sub>IH</sub>	HIGH-level input voltage		2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage		-	-	0.8	V
V <sub>OH</sub>	HIGH-level output	$V_{CC}$ = 2.7 V to 3.6 V; $I_{OH}$ = -100 $\mu$ A	V <sub>CC</sub> - 0.2	V <sub>CC</sub>	-	V
	voltage	$V_{CC} = 2.7 \text{ V; } I_{OH} = -8 \text{ mA}$	2.4	2.5	-	V
		$V_{CC} = 3.0 \text{ V; } I_{OH} = -32 \text{ mA}$	2.0	2.3	-	V
$V_{OL}$	LOW-level output	$V_{CC} = 2.7 \text{ V}; I_{OL} = 100 \mu\text{A}$	-	0.07	0.2	V
	voltage	V <sub>CC</sub> = 2.7 V; I <sub>OL</sub> = 24 mA	-	0.3	0.5	V
		V <sub>CC</sub> = 3.0 V; I <sub>OL</sub> = 16 mA	-	0.25	0.4	V
		V <sub>CC</sub> = 3.0 V; I <sub>OL</sub> = 32 mA	-	0.3	0.5	V
		V <sub>CC</sub> = 3.0 V; I <sub>OL</sub> = 64 mA	-	0.4	0.55	V
I <sub>OH</sub>	HIGH-level output current		-	-	-32	mA
I <sub>OL</sub>	LOW-level output current		-	-	32	mA
		current duty cycle ≤ 50%; f ≥ 1kHz	-	-	64	mA
$V_{OL(pu)}$	power-up LOW-level output voltage	$V_{CC} = 3.6 \text{ V}; I_O = 1 \text{ mA}; V_I = V_{CC} \text{ or GND}$ [2]	-	0.1	0.55	V
I <sub>I</sub>	input leakage current	all input pins				
		V <sub>CC</sub> = 0 V or 3.6 V; V <sub>I</sub> = 5.5 V	-	0.4	10	μA
		control pins				
		$V_{CC}$ = 3.6 V; $V_I$ = $V_{CC}$ or GND	-	±0.1	±1	μΑ
		data pins [3]				
		$V_{CC} = 3.6 \text{ V}; V_{I} = V_{CC}$	-	0.1	1	μΑ
		V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = 0 V	-	-0.4	-5	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_{CC} = 0 \text{ V}; V_{I} \text{ or } V_{O} = 0 \text{ V to } 4.5 \text{ V}$	-	0.1	±100	μΑ
I <sub>BHL</sub>	bus hold LOW current	nDn input; $V_{CC} = 3 \text{ V}$ ; $V_I = 0.8 \text{ V}$	75	135	-	μA
I <sub>BHH</sub>	bus hold HIGH current	nDn input; $V_{CC} = 3 \text{ V}$ ; $V_I = 2.0 \text{ V}$	-75	-135	-	μA
I <sub>BHLO</sub>	bus hold LOW overdrive current	nDn input; $V_{CC} = 3.6 \text{ V}$ ; $V_I = 0 \text{ V}$ to $3.6 \text{ V}$ [4]	500	-	-	μΑ
I <sub>BHHO</sub>	bus hold HIGH overdrive current	nDn input; $V_{CC} = 3.6 \text{ V}$ ; $V_I = 0 \text{ V}$ to $3.6 \text{ V}$ [4]	-	-	-500	μA

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Symbol	Parameter	Conditions		Min	Typ[1]	Max	Unit
I <sub>CEX</sub>	output high leakage current	nQn output in HIGH-state when $V_O > V_{CC}$ ; $V_O = 5.5 \text{ V}$ ; $V_{CC} = 3.0 \text{ V}$		-	50	125	μΑ
I <sub>O(pu/pd)</sub>	power-up/power-down output current	$V_{CC} \le 1.2 \text{ V}; V_O = 0.5 \text{ V to } V_{CC};$ $V_I = \text{GND or } V_{CC}; \text{ nOE} = \text{don't care}$	[5]	-	1	±100	μA
l <sub>OZ</sub>	OFF-state output current	$V_{CC}$ = 3.6 V; $V_I$ = $V_{IH}$ or $V_{IL}$					
		V <sub>O</sub> = 3.0 V		-	0.5	5	μA
		V <sub>O</sub> = 0.5 V		-	0.5	-5	μA
I <sub>CC</sub>	supply current	$V_{CC}$ = 3.6 V; $V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 A					
		output HIGH		-	0.07	0.12	mA
		output LOW		-	4.0	6	mA
		outputs disabled	[6]	-	0.07	0.12	mA
Δl <sub>CC</sub>	additional supply current	per input pin; $V_{CC}$ = 3.0 V to 3.6 V; one input at $V_{CC}$ - 0.6 V and other inputs at $V_{CC}$ or GND	[7]	-	0.1	0.2	mA
C <sub>I</sub>	input capacitance	V <sub>I</sub> = 0 V or 3.0 V		-	3	-	pF
Co	output capacitance	outputs disabled; V <sub>O</sub> = 0 V or 3.0 V		-	9	-	pF

- [1] All typical values are measured at  $V_{CC}$  = 3.3 V and  $T_{amb}$  = 25 °C.
- [2] For valid test results, data must not be loaded into the latches after applying power.
- [3] Unused pins at V<sub>CC</sub> or GND.
- [4] This is the bus hold overdrive current required to force the input to the opposite logic state.
- [5] This parameter is valid for any  $V_{CC}$  between 0 V and 1.2 V with a transition time of up to 10 ms. From  $V_{CC}$  = 1.2 V to  $V_{CC}$  = 3.3 V  $\pm$  0.3 V a transition time of 100  $\mu$ s is permitted. This parameter is valid for  $T_{amb}$  = 25 °C only.
- [6]  $I_{CC}$  is measured with outputs pulled to  $V_{CC}$  or GND.
- [7] This is the increase in supply current for each input at the specified voltage level other than V<sub>CC</sub> or GND.

### 10. Dynamic characteristics

**Table 7. Dynamic characteristics** 

At recommended operating conditions; Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 9.

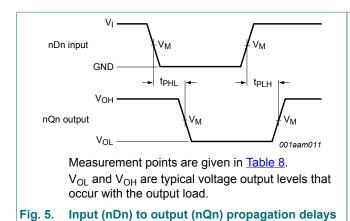
Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
t <sub>PLH</sub>	LOW to HIGH	nDn to nQn; see Fig. 5				
	propagation delay	V <sub>CC</sub> = 2.7 V	-	-	4.5	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.5	1.8	3.9	ns
t <sub>PHL</sub>	HIGH to LOW	nDn to nQn; see Fig. 5				
	propagation delay	V <sub>CC</sub> = 2.7 V	-	-	4.5	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.5	1.9	3.9	ns
t <sub>PLH</sub>	LOW to HIGH	nLE to nQn; see Fig. 6				
	propagation delay	V <sub>CC</sub> = 2.7 V	-	-	5.4	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.5	2.1	4.8	ns
t <sub>PHL</sub>	HIGH to LOW	nLE to nQn; see Fig. 6				
	propagation delay	V <sub>CC</sub> = 2.7 V	-	-	5.4	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.5	2.2	4.8	ns
t <sub>PZH</sub>	OFF-state to HIGH	nOE to nQn; see Fig. 7				
	propagation delay	V <sub>CC</sub> = 2.7 V	-	-	5.1	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.1	2.8	4.5	ns
t <sub>PZL</sub>	OFF-state to LOW	nOE to nQn; see Fig. 7				
	propagation delay	V <sub>CC</sub> = 2.7 V	-	-	4.7	ns

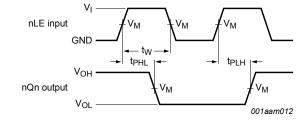
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Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.1	2.6	4.3	ns
t <sub>PHZ</sub>	HIGH to OFF-state	nOE to nQn; see Fig. 7				
	propagation delay	V <sub>CC</sub> = 2.7 V	-	-	5.1	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.1	0.1 2.6 4.3	4.5	ns
$t_{PLZ}$	LOW to OFF-state	nOE to nQn; see Fig. 7				
	propagation delay	V <sub>CC</sub> = 2.7 V	-	-	4.7	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.1	3.0	4.3	ns
t <sub>su(H)</sub>	set-up time HIGH	nDn to nLE; see Fig. 8				
		V <sub>CC</sub> = 2.7 V	1.0	-	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.5	0.1	-	ns
t <sub>su(L)</sub>	set-up time LOW	nDn to nLE; see Fig. 8				
		V <sub>CC</sub> = 2.7 V	2.0	-	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	0.2	-	ns
t <sub>h(H)</sub>	hold time HIGH	nDn to nLE; see Fig. 8				
		V <sub>CC</sub> = 2.7 V	1.0	-	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.0	0	-	ns
t <sub>h(L)</sub>	hold time LOW	nDn to nLE; see Fig. 8				
		V <sub>CC</sub> = 2.7 V	2.0	-	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.5	0	-	ns
t <sub>WH</sub>	pulse width HIGH	nLE; see Fig. 6				
		V <sub>CC</sub> = 2.7 V	1.5	-	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.5	0.5	-	ns

<sup>[1]</sup> Typical values are at  $V_{CC}$  = 3.3 V and  $T_{amb}$  = 25 °C.

### 10.1. Waveforms and test circuit





Measurement points are given in <u>Table 8</u>.  $V_{OL}$  and  $V_{OH}$  are typical voltage output levels that occur with the output load.

Fig. 6. Latch enable input (nLE) to data output (nQn) propagation delays and pulse width

#### 3.3 V 16-bit transparent D-type latch; 3-state

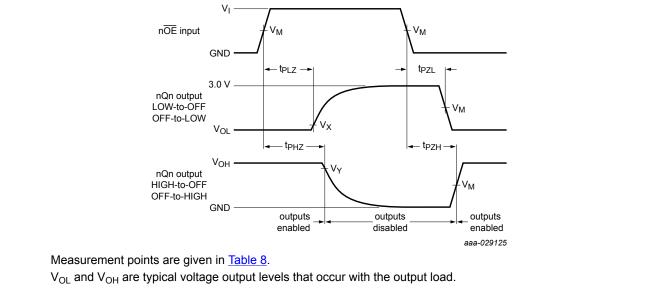
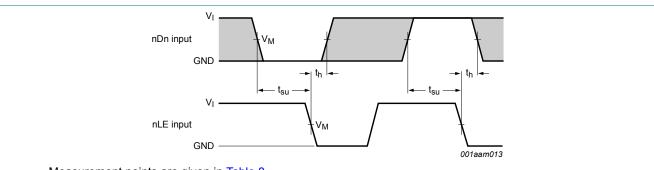


Fig. 7. OFF-state to HIGH or LOW and HIGH or LOW to OFF-state propagation delays



Measurement points are given in Table 8.

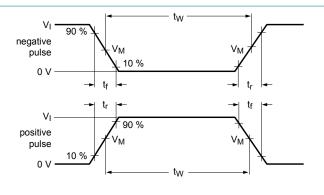
The shaded areas indicate when the input is permitted to change for predictable output performance.

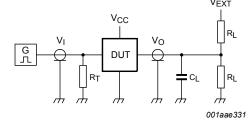
Fig. 8. Input (nDn) to output (nLE) data set-up and hold times

**Table 8. Measurement points** 

Input		Output						
V <sub>I</sub>	ı V <sub>M</sub>		V <sub>X</sub>	V <sub>Y</sub>				
2.7 V	1.5 V	1.5 V	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> - 0.3 V				

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Test data is given in Table 9.

Definitions test circuit:

 $R_L$  = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to output impedance  $Z_0$  of the pulse generator.

 $V_{EXT}$  = Test voltage for switching times.

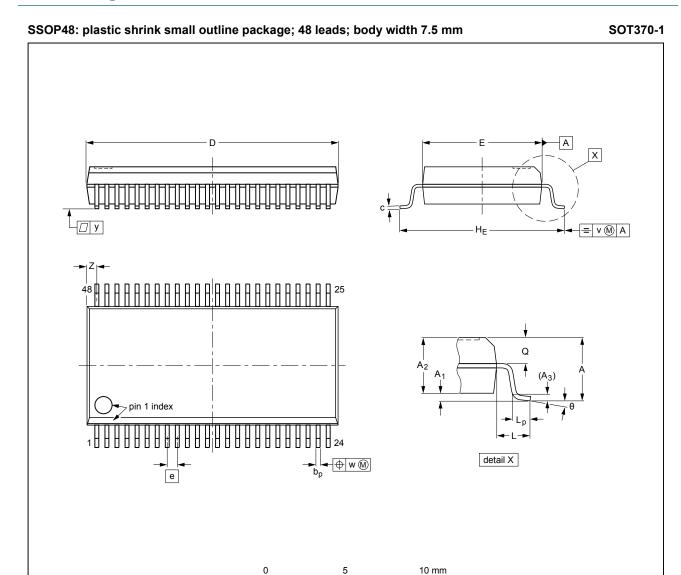
Fig. 9. Test circuit for measuring switching times

Table 9. Test data

Input				Load		V <sub>EXT</sub>			
VI	f <sub>i</sub> t <sub>W</sub>		t <sub>r</sub> , t <sub>f</sub>	CL	$R_L$	t <sub>PHZ</sub> , t <sub>PZH</sub>	$t_{PLZ},t_{PZL}$	t <sub>PLH</sub> , t <sub>PHL</sub>	
2.7 V	≤ 10 MHz	500 ns	≤ 2.5 ns	50 pF	500 Ω	GND	6 V	open	

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### 11. Package outline



#### **DIMENSIONS** (mm are the original dimensions)

U	JNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
ı	mm	2.8	0.4 0.2	2.35 2.20	0.25	0.3 0.2	0.22 0.13	16.00 15.75	7.6 7.4	0.635	10.4 10.1	1.4	1.0 0.6	1.2 1.0	0.25	0.18	0.1	0.85 0.40	8° 0°

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN	ISSUE DATE
	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT370-1		MO-118				<del>99-12-27</del> 03-02-19

Fig. 10. Package outline SOT370-1 (SSOP48)

#### 3.3 V 16-bit transparent D-type latch; 3-state

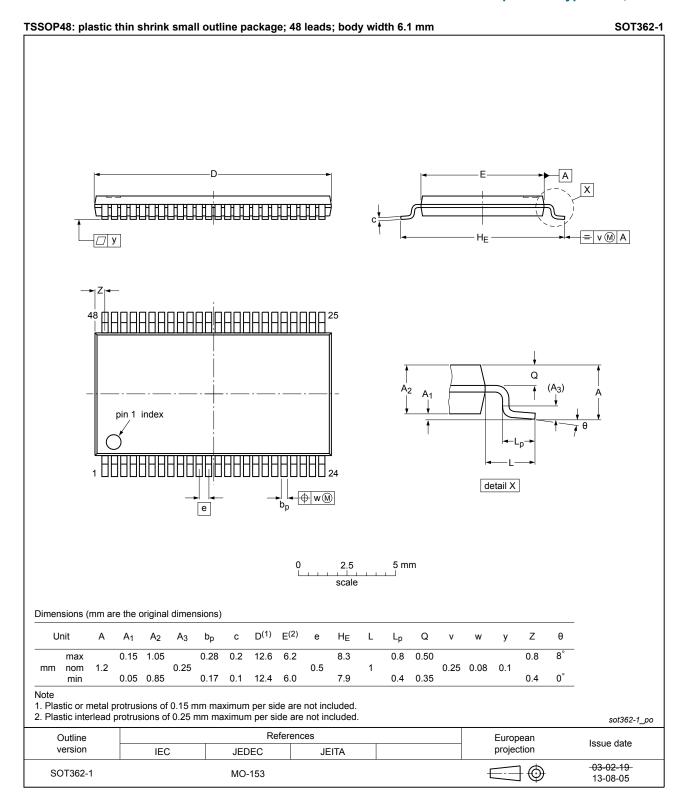


Fig. 11. Package outline SOT362-1 (TSSOP48)

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### 12. Abbreviations

#### **Table 10. Abbreviations**

Acronym	Description
BiCMOS	Bipolar Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
MIL	Military
MM	Machine Model
TTL	Transistor-Transistor Logic

### 13. Revision history

#### **Table 11. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVT16373A v.3	20181001	Product data sheet	-	74LVT16373A v.2
Modifications:	Nexperia.	of this data sheet has been remarked been adapted to the new		ith the identity guidelines of re appropriate.
74LVT16373A v.2	19980219	Product specification	-	74LVT16373A v.1
74LVT16373A v.1	19941215	Product specification	-	-

### 14. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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### 3.3 V 16-bit transparent D-type latch; 3-state

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